

Nanoscale Energy Conversion by Selective Electron Emission: A New Paradigm or Maxwell's Demon Revisited?

Energy and Nanotechnology: Strategy for the Future

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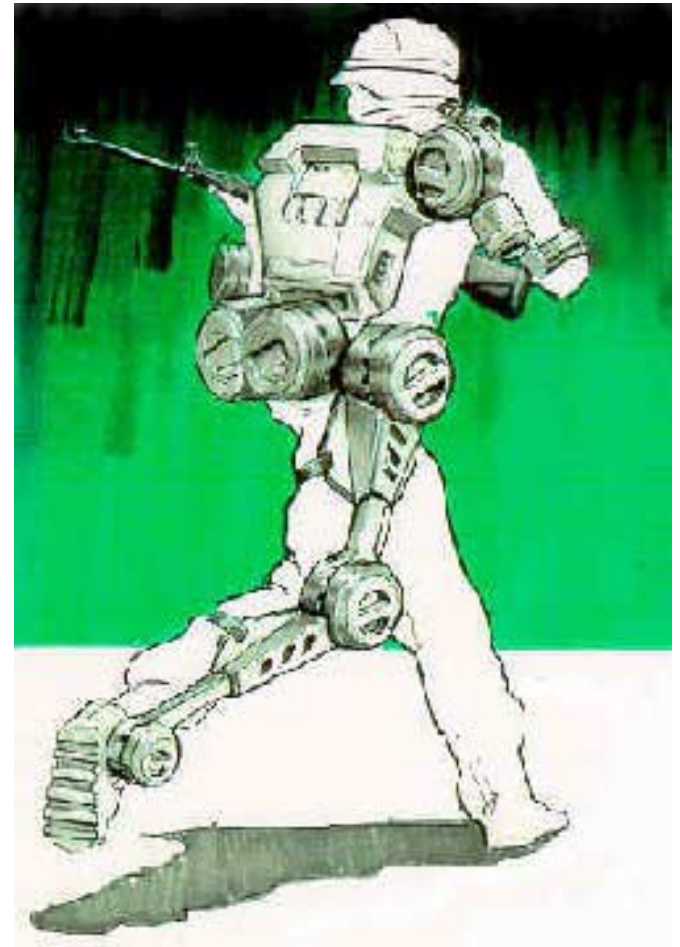
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Outline

- Direct energy conversion
- Energy transport in electron emission processes
 - Thermal-field emission
 - Thermionic emission
- Conclusions

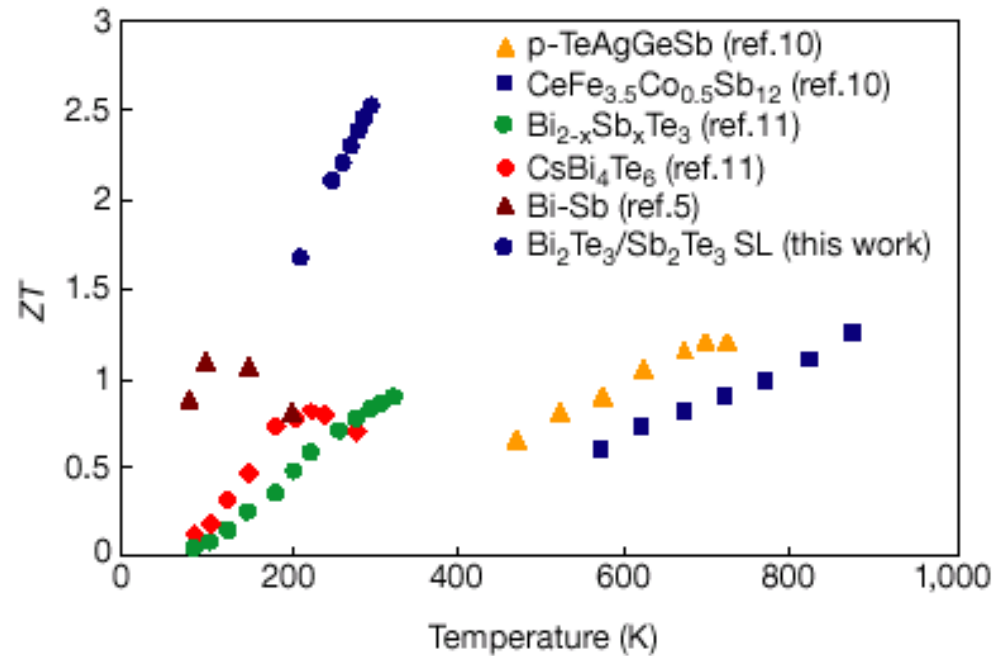
Direct Energy Conversion

- Direct thermal-electrical conversion eliminates moving parts
 - Enhanced reliability
 - Traditionally low conversion efficiency
- Short-term opportunities
 - Solar-thermal power generation
 - Man-portable power generation and cooling
 - Electronics cooling
 - Radioisotope power generation
- Longer-term opportunities
 - Topping cycles for fossil fuel plants
 - Bottoming cycles for fuel cells, exhaust systems

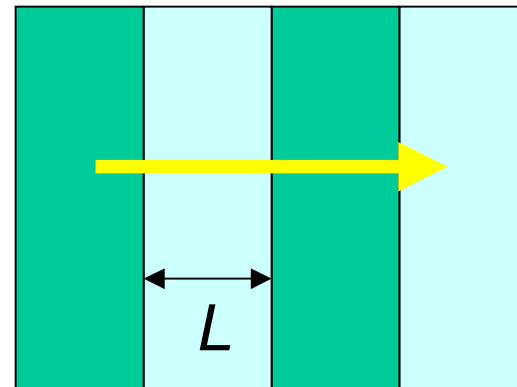


Nanoscale Thermoelectrics

- Figure of merit ZT
 - Indicates thermodynamic efficiency
 - Typical bulk values $ZT \sim 1$
 - Enhanced by nanoscale spatial confinement
- Measured $ZT = 2.4$ for $10\text{\AA}/50\text{\AA}$ $\text{Bi}_2\text{Te}_3/\text{Sb}_2\text{Te}_3$ superlattices (Venkatasubramanian et al., 2001)
 - Coefficient of performance approximately 2-3 for room temperature refrigeration
- Nanowires (Hicks and Dresselhaus, 1993)
 - Extrapolation of model to $ZT \sim 4$



Thin-film superlattice

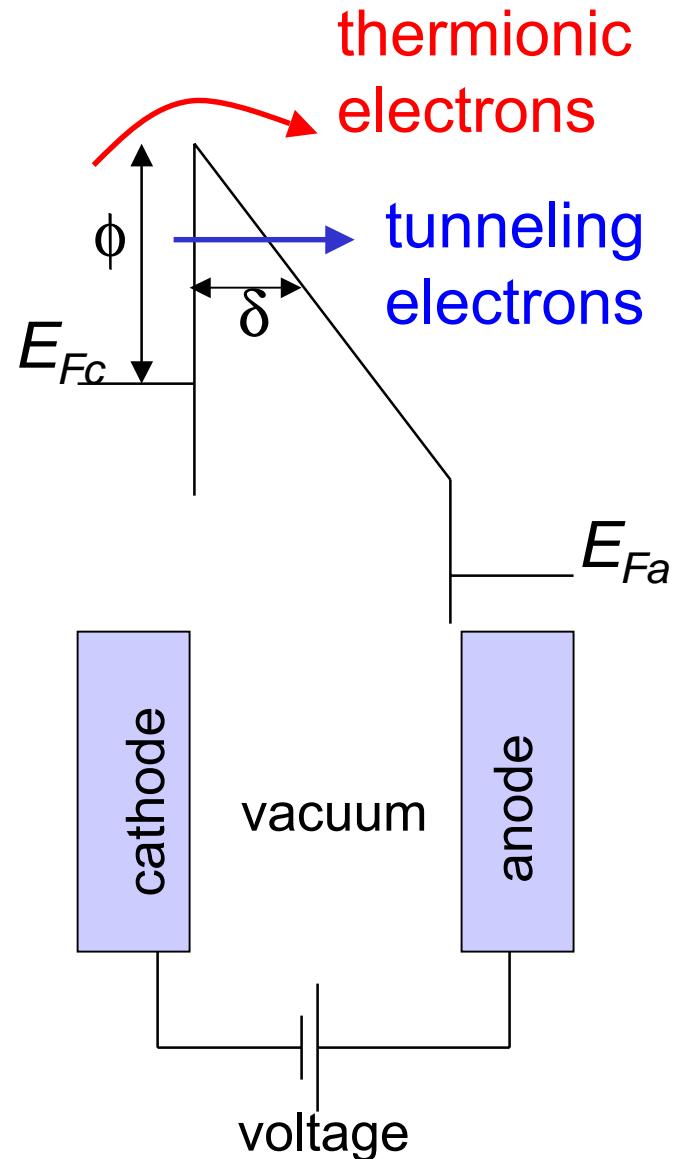


Electron Emission Processes

- Electron can emit over potential barriers (**thermionic emission**), OR
- They can tunnel through them (**field emission**)
- First studied in detail by Fowler and Nordheim (1928) for metal-vacuum-metal structures
- Emission is a strong function of field strength
- Tunneling probability

$$T \propto e^{-\delta}$$

δ = local barrier thickness

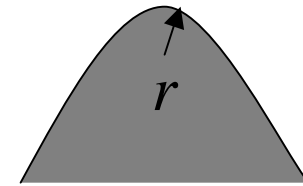


Geometric Field Enhancement

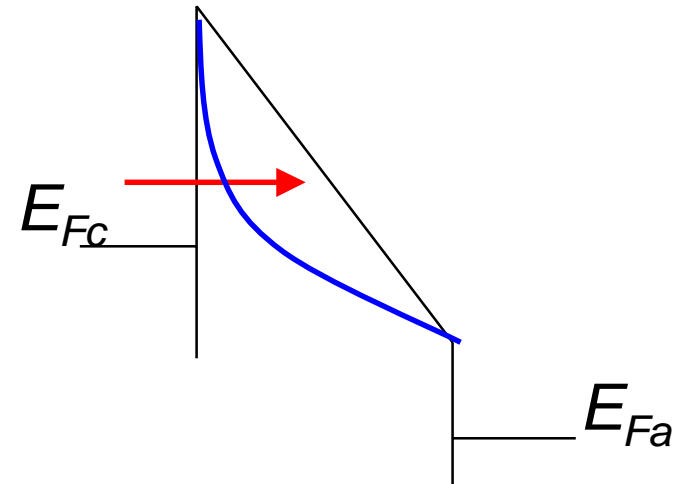
- Spindt (1968) created micron-sized metallic tips to enhance field emission

$$F_{local} = \beta F_{ave} \sim F_{ave} / r$$

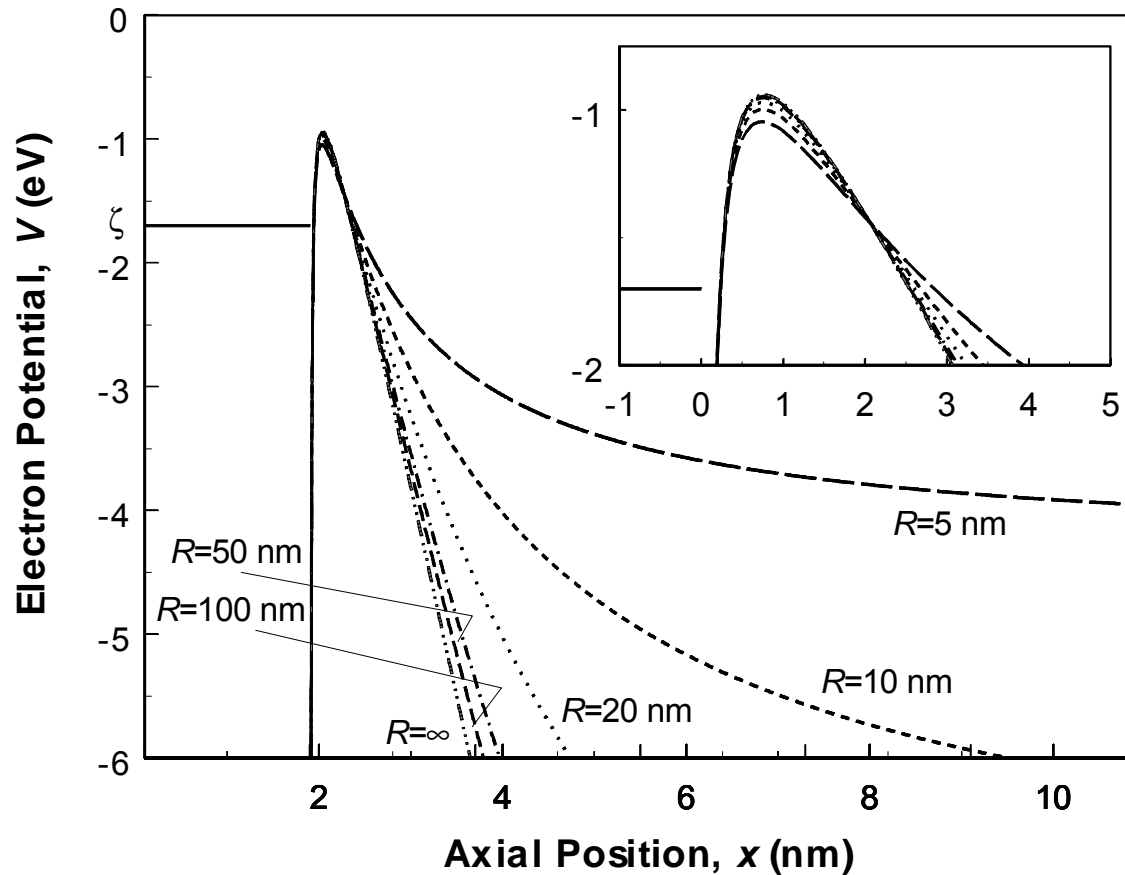
β = Field enhancement factor



- Field enhancement is predicted by electrostatic theory



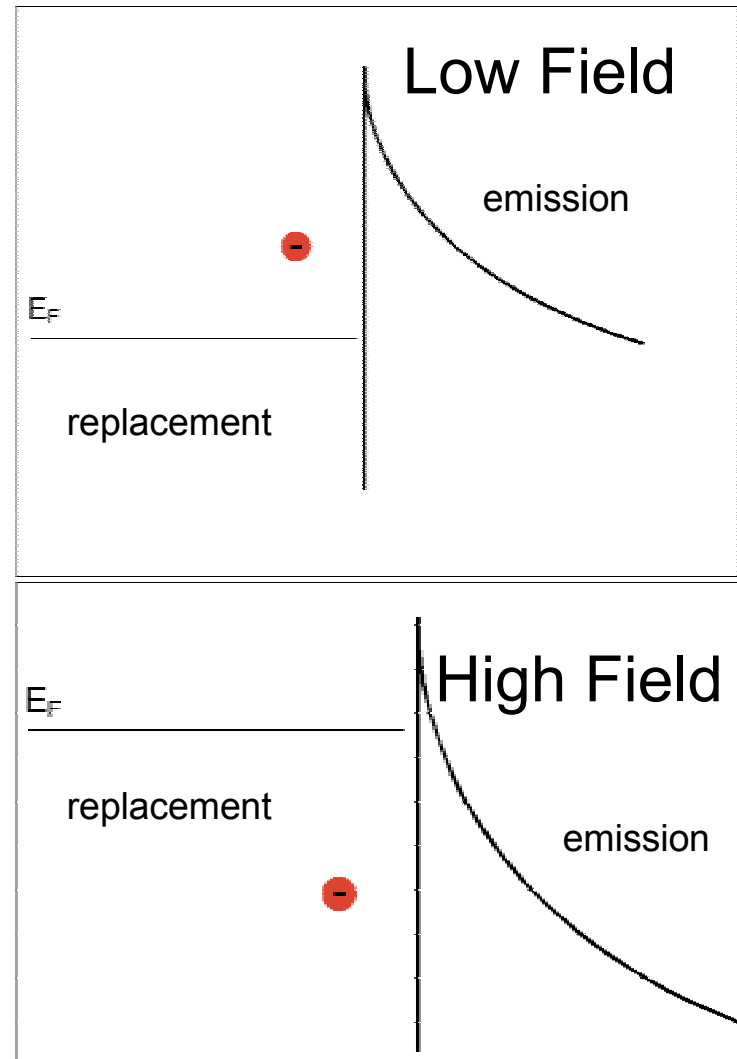
Nanoscale Effects on Emission



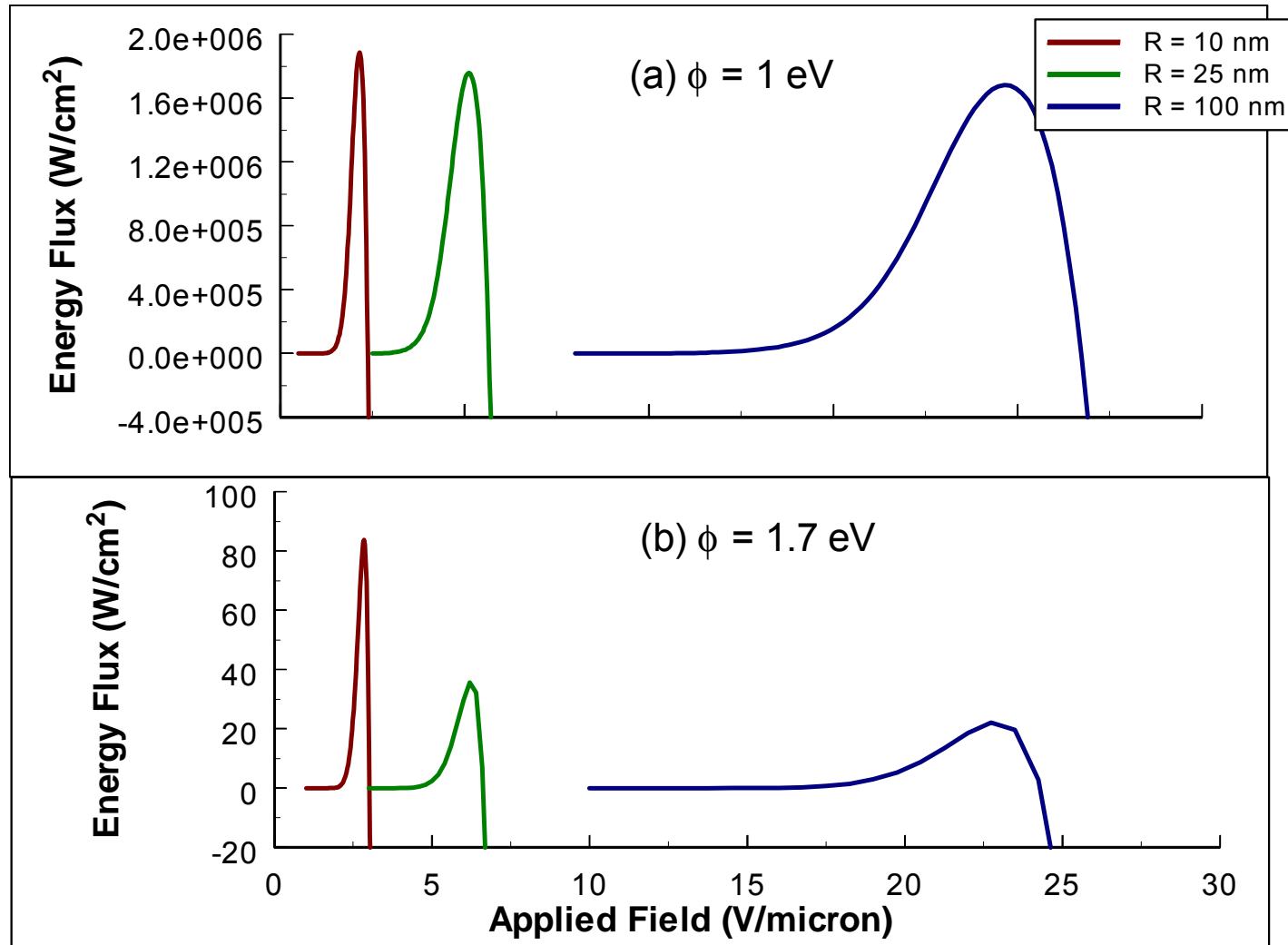
Effect of emitter radius on potential profile as a function of position from emitter and emitter radius. All profiles produce the same current density, $J = 10 \text{ A/cm}^2$. $\phi = 1.7 \text{ eV}$. $T = 300 \text{ K}$. (Fisher, 2001)

Energy Exchange

- Average emitted electron energies from moments of emission integral
 - Can be higher or lower than replacement electrons, depending on the field strength and curvature
- Replacement electrons from charge conservation and availability of states



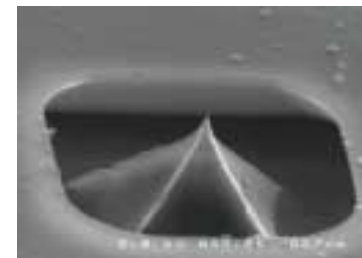
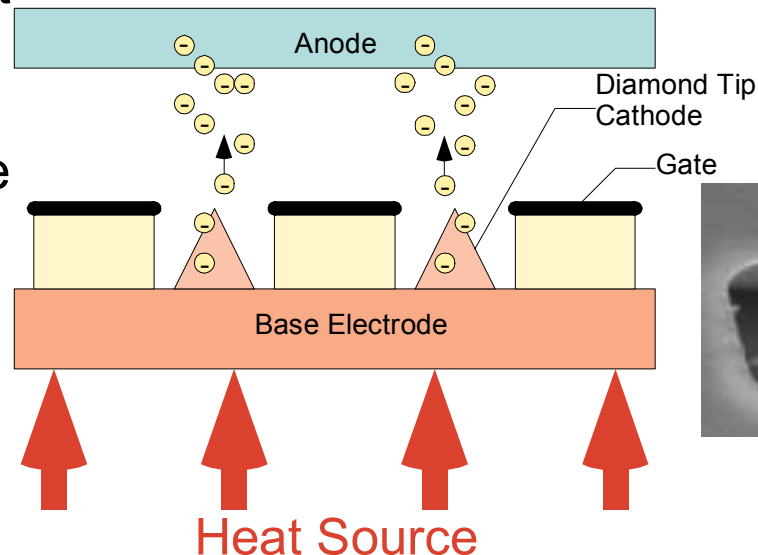
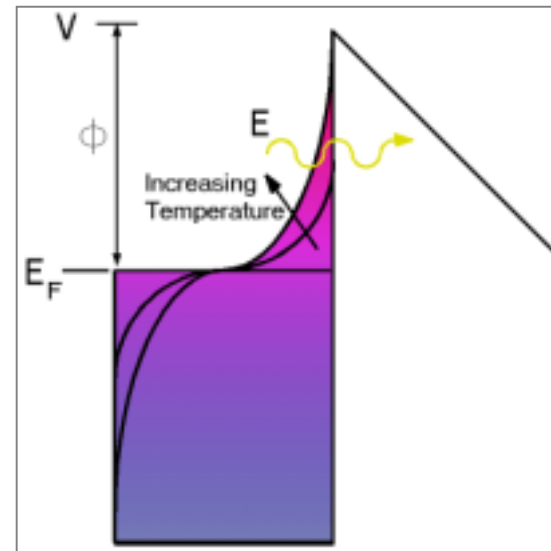
Predicted Net Energy Flux



Emission energy flux from the cathode as a function applied field F , emitter characteristic radius R , and work function ϕ . (a) $\phi = 1$ eV. (b) $\phi = 1.7$ eV. Each part shows curves for three emitter radii, $R = 10, 25,$ and 100 nm. Temperature $T = 300$ K. (Fisher and Walker, 2002)

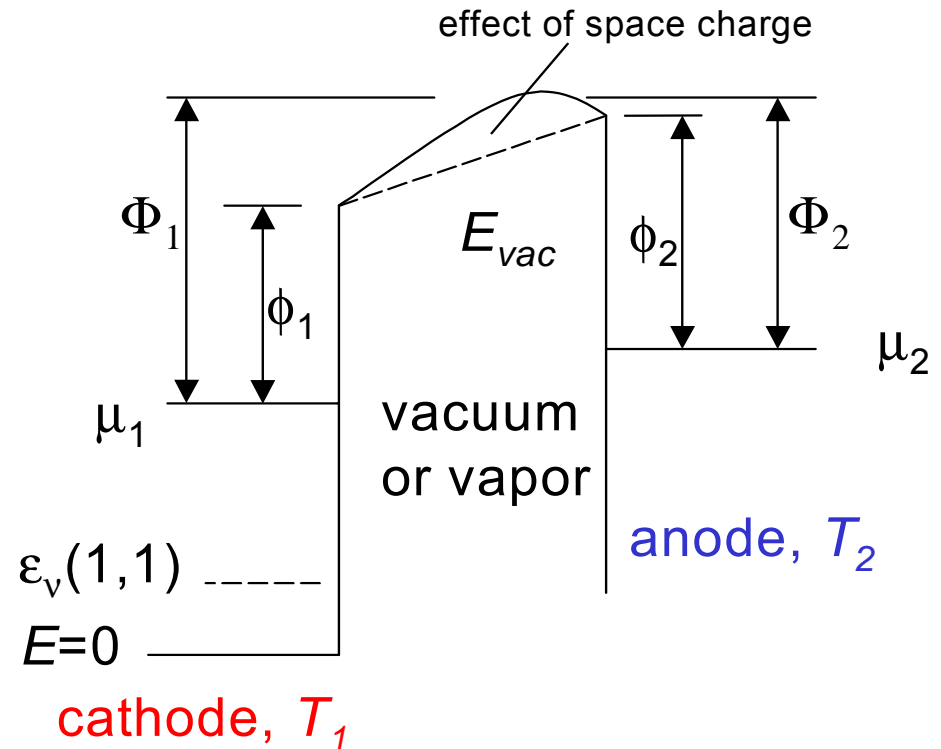
Thermionic Emission

- Observed first by Edison (1880s)
- Current density derived by Richardson (1912)
- Thermal-to-electrical power generation
 - Low-energy-replacement electrons excited by heat source
 - Heat applied to a nanostructured substrate
 - Electrons excited to higher energy states
 - High energy electrons emitted to anode
 - Energy is dissipated across a load



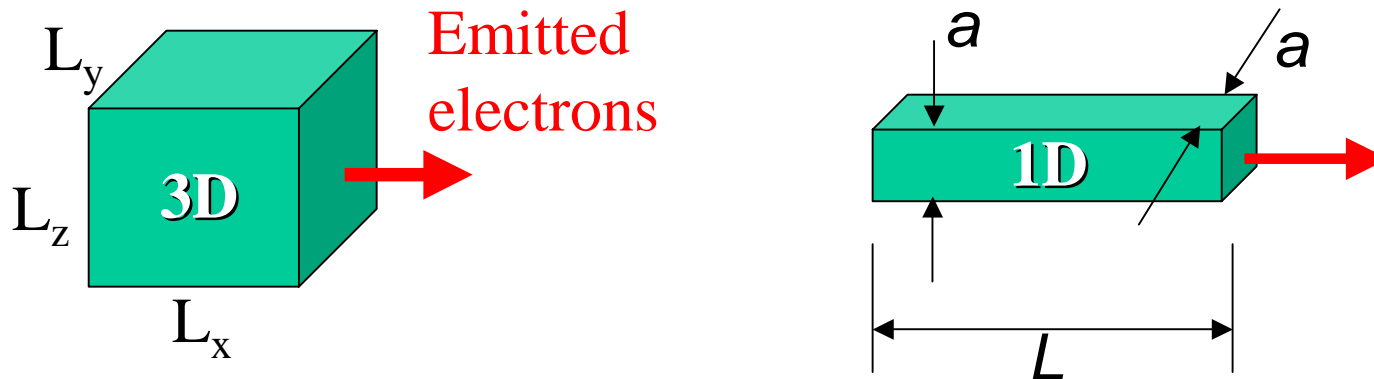
Thermionic Device Operation

- Electrons thermally excited above the chemical potential μ according to the Fermi-Dirac distribution function
- At a material surface, electrons may escape the material if their energy exceeds the work function
- Additional potential barriers exist due to space charge and generated voltage



Electron motive diagram for a thermionic power generation diode, with $T_1 > T_2$.

Quantum Confinement Effects



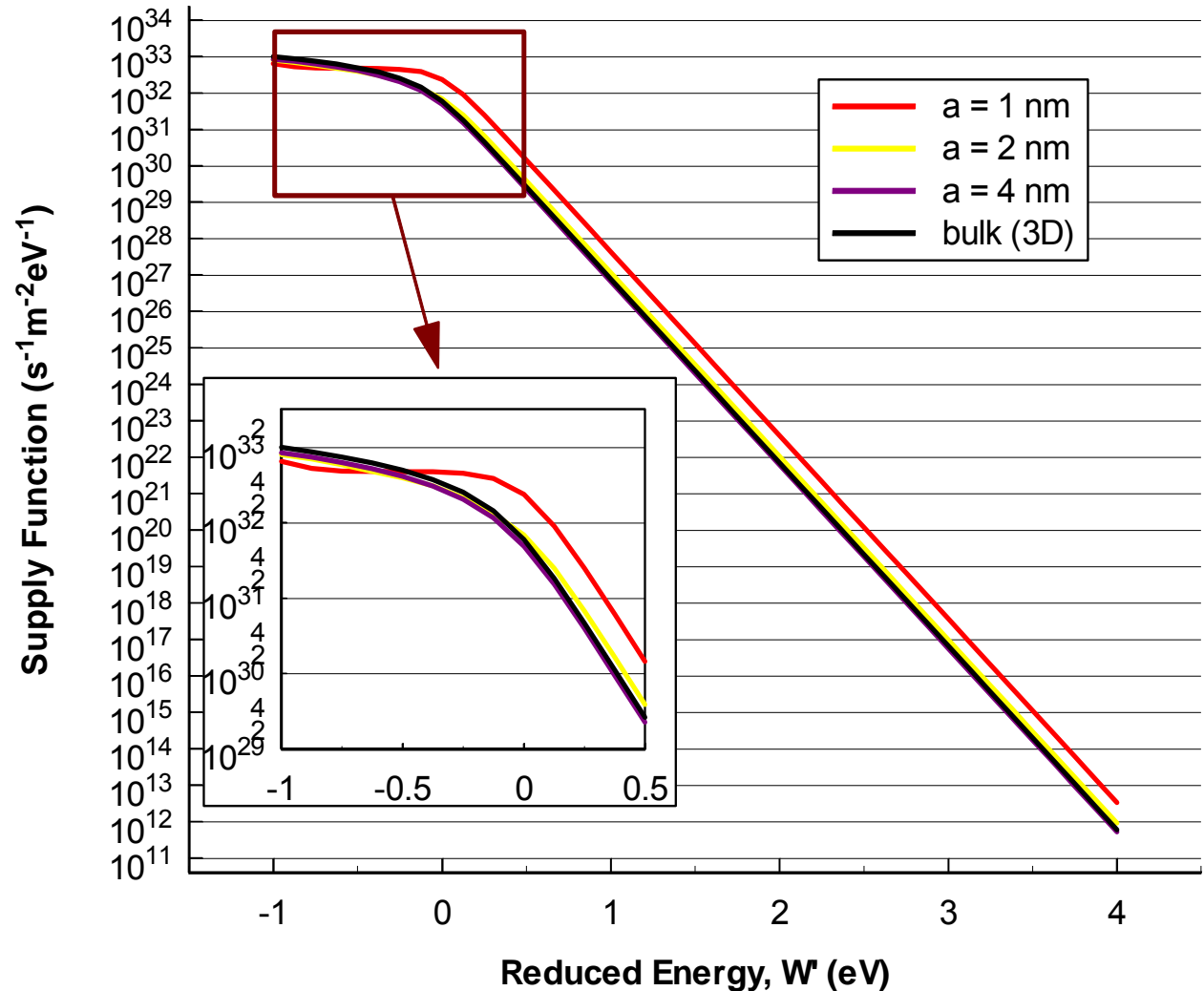
- Confinement influences energy states of electrons

$$E_{3D} = \frac{\hbar^2}{2m} (k_x^2 + k_y^2 + k_z^2)$$

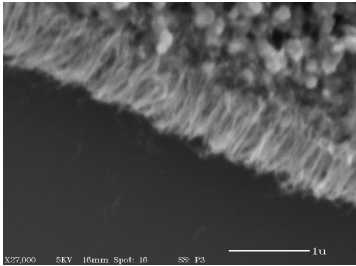
$$E_{1D} = \frac{\hbar^2}{2m} (k_x^2) + \frac{\left(\frac{\hbar\pi}{a}\right)^2}{2m} (n_y^2 + n_z^2), \quad n_{y,z} = \text{integer}$$

Electron Supply Function

- Supply function gives number of electrons striking the emitting surface per unit time, area, and energy
- Noticeable increase in high-energy supply function for 1 nm quantum wire
- Larger wires are similar to bulk



Toy Example: Isothermal Power Generation

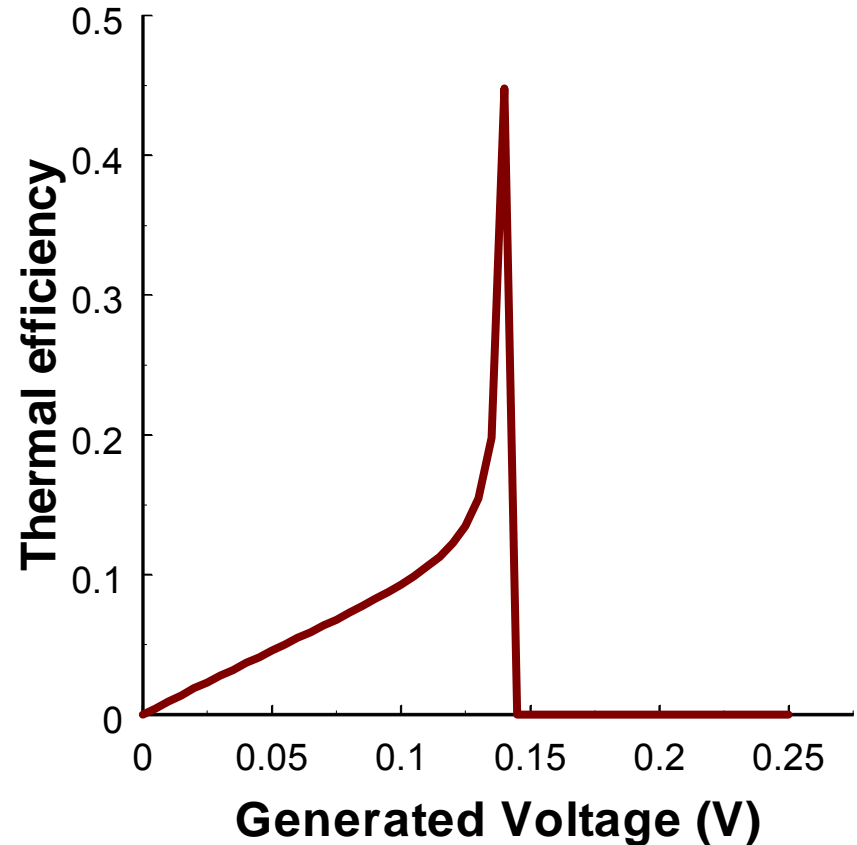


aligned CNT array



array of closely packed, aligned nanowires

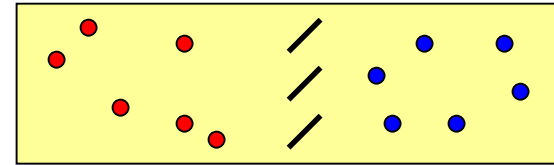
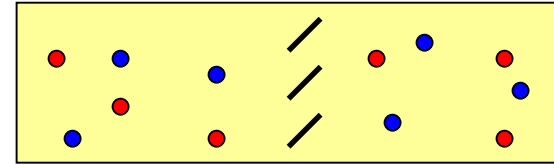
- 2nd law of thermodynamics requires null thermal efficiency
- Simple theory predicts net power generation



Is This Notion Possible?

➤ Concept is similar to Maxwell's demon

- High-energy particles separated from low energy particles by a lossless “shutter”

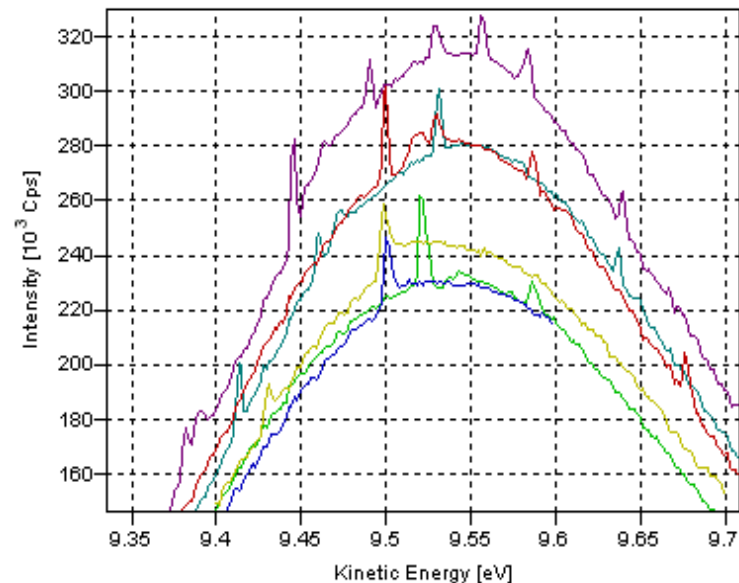
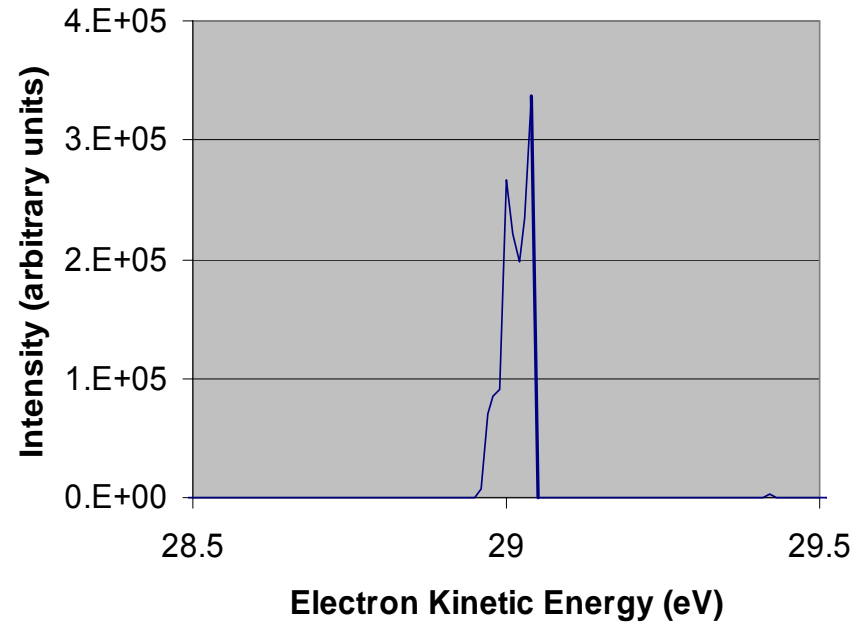


➤ Can nanomaterials serve as such separators?

- Many unknowns
 - Nature of interfacial transport from 3D to 1D
 - Interactions among quantum wires
 - Internal loss (scattering) mechanisms
- Answer: probably not, but...
 - Perhaps we can approach 2nd law limits differently

Experimental Characterization

- Emitted electron energy distribution measurements
 - Room temp field emission from diamond nanotip
 - Thermionic emission from nanocrystalline diamond ($T \approx 970\text{-}980^\circ\text{C}$)



Prospects for Energy Conversion

- Direct energy conversion still in niche markets
 - Broader application will require higher efficiencies
 - Manufacturing economies of scale not competitive
- Nanoscale materials
 - All concepts require low work functions
 - Materials development required in surface science, combinatorial materials, controlled synthesis
- Many challenges
 - Understanding of transport at interfaces between bulk and confined materials
 - Non-uniform material behavior → must scale up from nano to macro
- Potential for exceptional performance
 - Generally high power density
 - **Helpful Quantum Effects?**

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